

N-channel 25 V, 1.0 mΩ, 240 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology 23 June 2020 Product d

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package. NextPowerS3 portfolio utilising Nexperia's unique "SchottkyPlus" technology delivers high efficiency, low spiking performance usually associated with MOSFETS with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- Avalanche rated, 100% tested at I_{AS} = 190 A
- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- Superfast switching with soft-recovery
- Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 μA leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Power SO8 package; no glue, no wire bonds, qualified to 175 °C
- Wave solderable; exposed leads for optimal visual solder inspection

3. Applications

- On-board DC:DC solutions for server and telecommunications
- · Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- Brushed and brushless motor control
- Power OR-ing

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	25	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	240	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	160	W
Tj	junction temperature			-55	-	175	°C
Static chara	cteristics		·				
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	0.89	1	mΩ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	1.19	1.43	mΩ
Dynamic ch	aracteristics						
Q _{GD}	gate-drain charge	I_D = 25 A; V_{DS} = 12 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13		-	8	-	nC
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 12; Fig. 13		-	71.8	-	nC
Avalanche r	ruggedness			-1			
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\label{eq:linear} \begin{array}{l} I_D = 25 \; A; \; V_{sup} \leq \; 25 \; V; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; V; \; T_{j(init)} = 25 \; ^\circ C; \; unclamped; \\ t_p = 4.34 \; ms \end{array}$	[2] [3]	-	-	1762	mJ
Source-drai	in diode	·					
Q _r	recovered charge	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 12 \text{ V}; \frac{\text{Fig. 16}}{16}$	[4]	-	36.7	-	nC

[1] 240A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] includes capacitive recovery

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source	a	G_↓Ħ♪
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN1R0-25YLD	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R0-25YLD	1D025L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

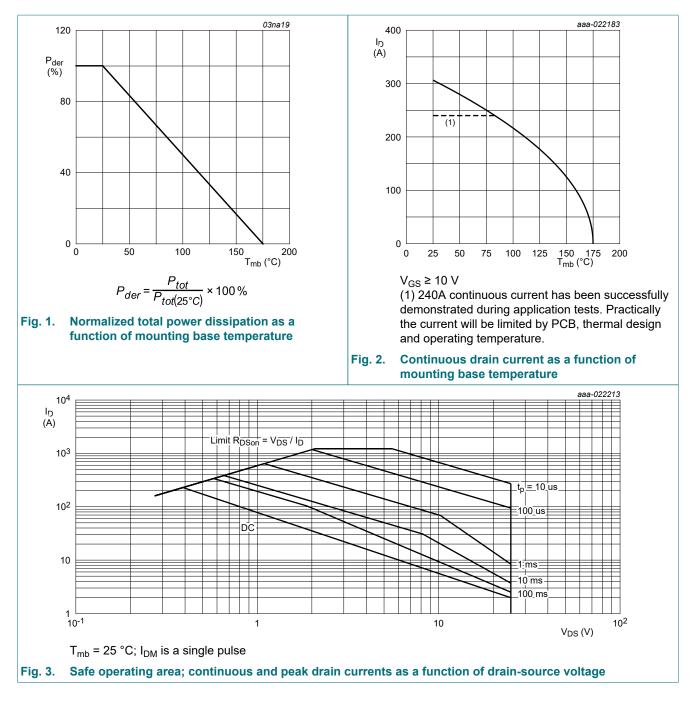
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	25	V
V _{DGR}	drain-gate voltage	25 °C ≤ T _j ≤ 175 °C; R _{GS} = 20 kΩ		-	25	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	160	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	240	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	216	А
I _{DM}	peak drain current	t _p ≤ 10 μs; <u>Fig. 3</u>		-	1226	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
V _{ESD}	electrostatic discharge voltage	НВМ		1700	-	V
Source-drai	n diode	1				
I _S	source current	T _{mb} = 25 °C		-	133	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1226	А
Avalanche r	uggedness	1				
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 25 A; V _{sup} ≤ 25 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; t _p = 4.34 ms	[2] [3]	-	1762	mJ
I _{AS}	non-repetitive avalanche current		[4]	-	190	A

[1] 240A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

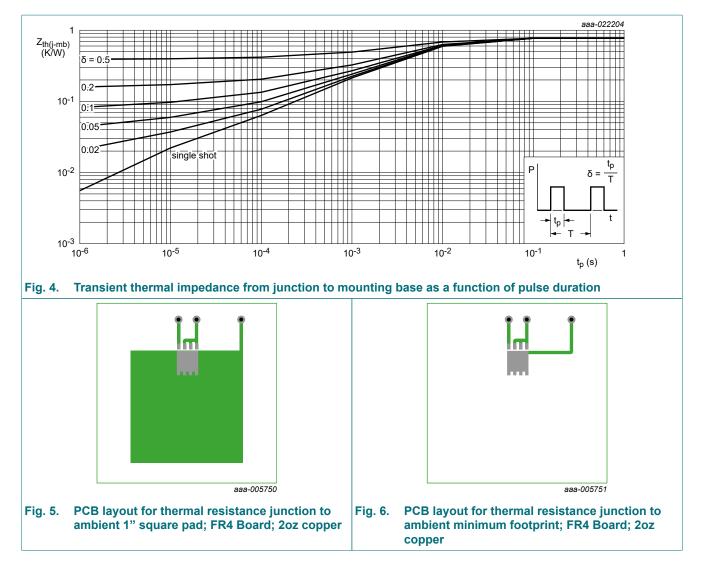
[3] Refer to application note AN10273 for further information.

[4] Protected by 100% test.



9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>	-	0.68	0.94	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	50	-	K/W
	junction to ambient	Fig. 6	-	125	-	K/W

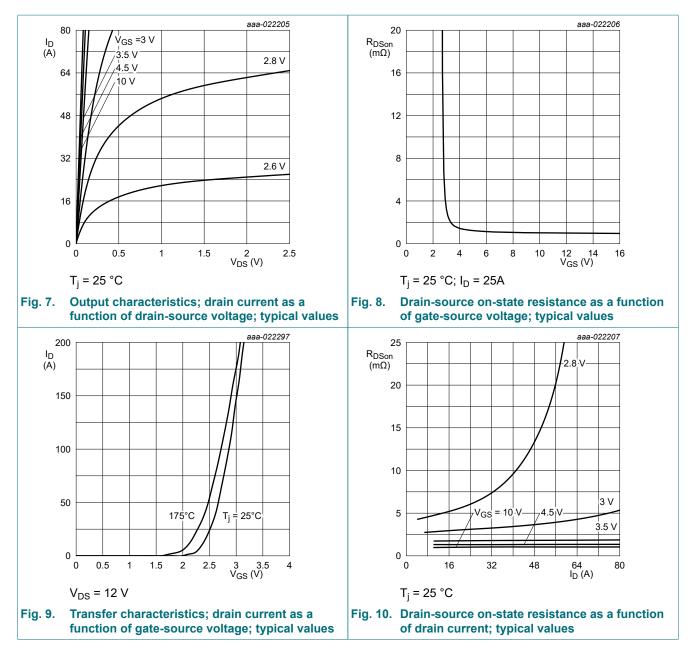


10. Characteristics

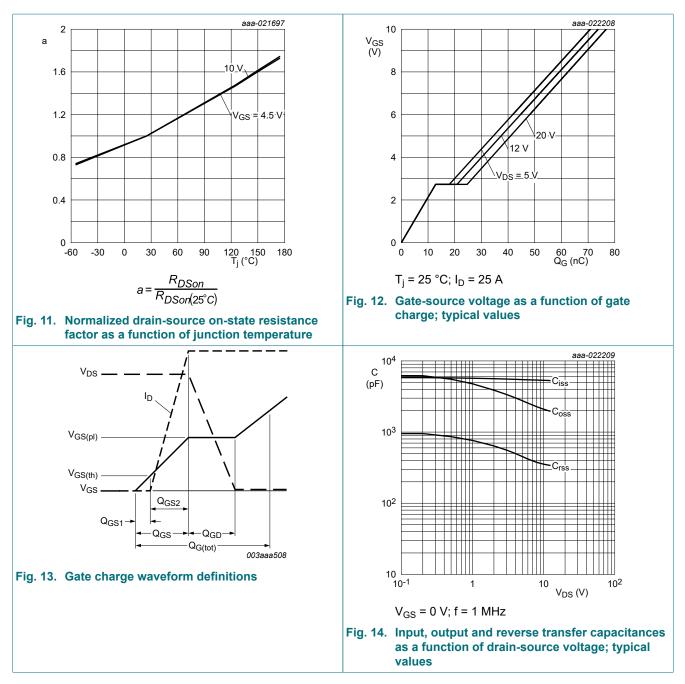
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics	, , ,	I			
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	25	-	-	V
、 ,	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	22.5	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.75	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 175 °C	-	-5	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C	-	29.7	-	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _i = 25 °C	-	-	100	nA

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	0.89	1	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; <u>Fig. 10; Fig. 11</u>		-	-	1.7	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	1.19	1.43	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11		-	-	2.43	mΩ
R _G	gate resistance	f = 1 MHz		-	1.14	-	Ω
Dynamic ch	aracteristics					_	
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13		-	71.8	-	nC
	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	33.2	-	nC	
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V		-	39.7	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		-	12.9	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		-	7.8	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	5.1	-	nC
Q _{GD}	gate-drain charge			-	8	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.7	-	V
C _{iss}	input capacitance	V _{DS} = 12 V; V _{GS} = 0 V; f = 1 MHz;		-	5308	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	1979	-	pF
C _{rss}	reverse transfer capacitance			-	342	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 12 \text{ V}; \text{ R}_{L} = 0.6 \Omega; \text{ V}_{GS} = 4.5 \text{ V};$		-	30.3	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	36	-	ns
t _{d(off)}	turn-off delay time			-	34	-	ns
t _f	fall time			-	24.5	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 12 V; f = 1 MHz; T _j = 25 °C		-	36.4	-	nC
Source-drai	in diode						
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 15</u>		-	0.79	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	36.9	-	ns
Q _r	recovered charge	V _{DS} = 12 V; <u>Fig. 16</u>	[1]	-	36.7	-	nC
t _a	reverse recovery rise time			-	19.2	-	ns
t _b	reverse recovery fall time			-	17.7	-	ns
S	softness factor			-	0.9	-	

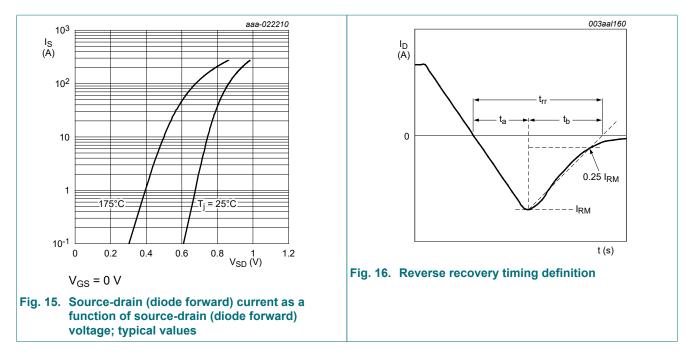
[1] includes capacitive recovery



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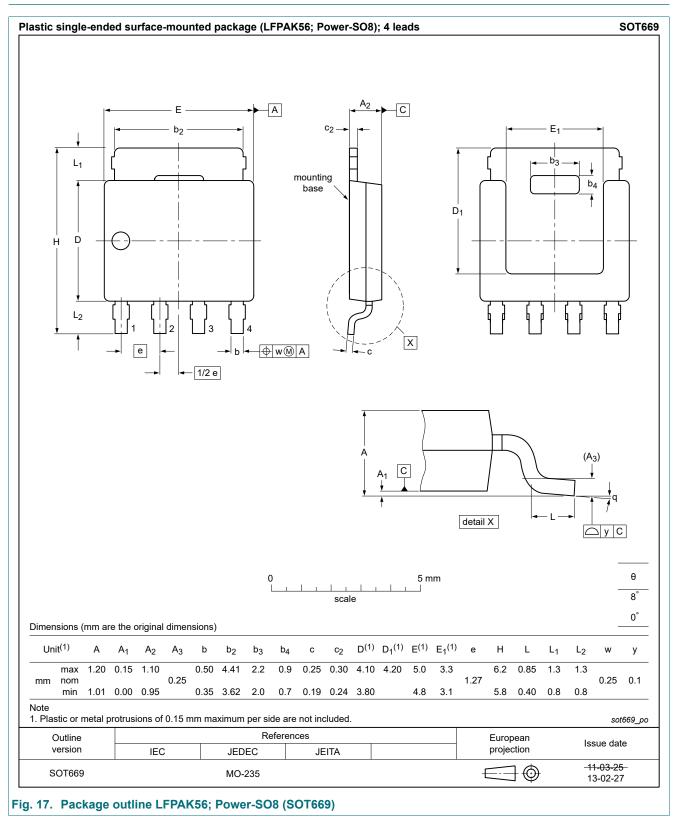


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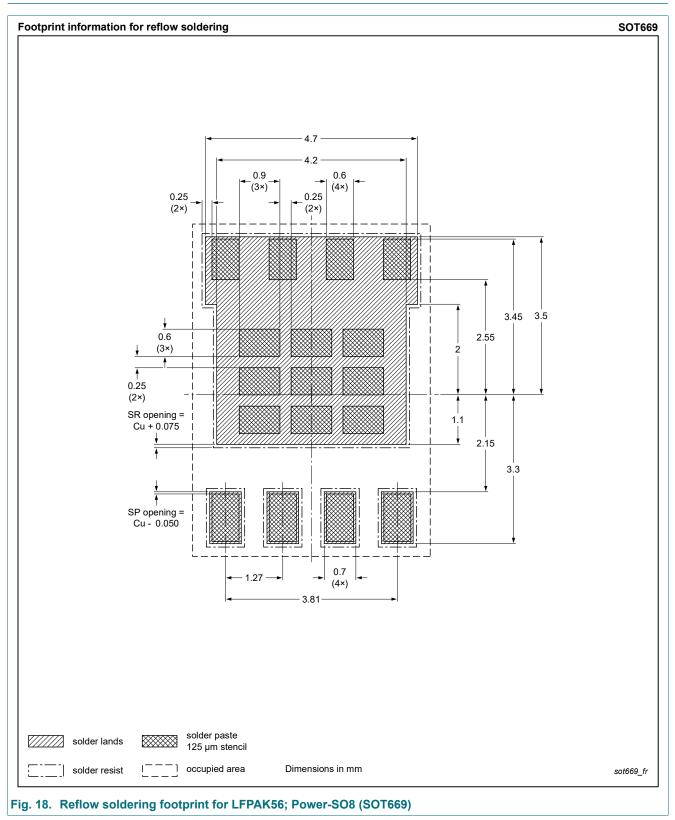


PSMN1R0-25YLD

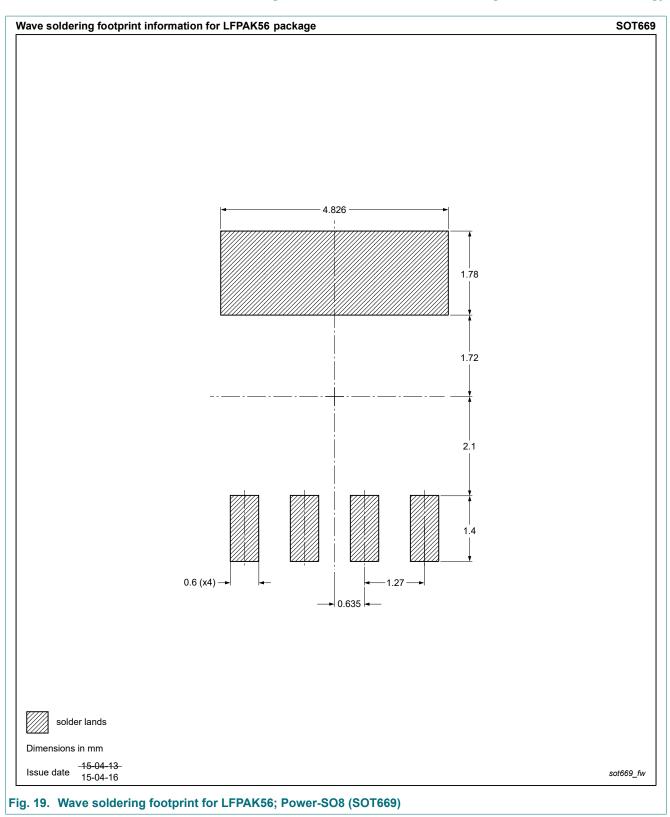
11. Package outline



12. Soldering



N-channel 25 V, 1.0 mΩ, 240 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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